


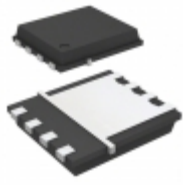
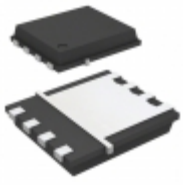
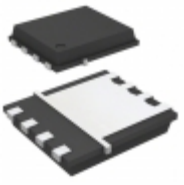
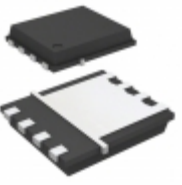
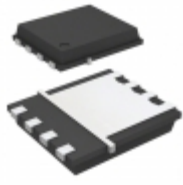
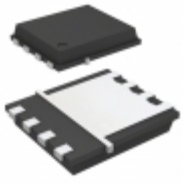
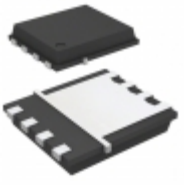
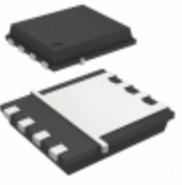
	<h2>FDMS0310AS</h2>
	<p>Hersteller-Teilenummer: FDMS0310AS</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 19A PT8</p> <p>Datenblätter:  FDMS0310AS.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 104909 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FDMS0310AS
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 30V 19A PT8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	104909 pcs Stock
Hersteller Standard Vorlaufzeit	26 Weeks
detaillierte Beschreibung	N-Channel 30V 19A (Ta), 22A (Tc) 2.5W (Ta), 41W
Serie	PowerTrench®, SyncFET™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-PowerTDFN
Supplier Device-Gehäuse	8-PQFN (5x6)
Verlustleistung (max)	2.5W (Ta), 41W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	19A (Ta), 22A (Tc)
Rds On (Max) @ Id, Vgs	4.3 mOhm @ 19A, 10V
VGS (th) (Max) @ Id	3V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	37nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2280pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	FDMS0310ASTR


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Sie können auch interessiert sein:

 <p>FDMS0310S AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 19A</p>	 <p>FDMS0310AS Fairchild/ON Semiconductor MOSFET N-CH 30V 19A PT8</p>	 <p>FDMS030N06B Fairchild/ON Semiconductor MOSFET N-CH 60V 22.1A POWER56</p>	 <p>FDMS0309AS AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 21A PT8</p>
 <p>FDMS0310S Fairchild/ON Semiconductor MOSFET N-CH 30V 19A</p>	 <p>FDMS0312AS AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 18A PT8</p>	 <p>FDMS0312AS Fairchild/ON Semiconductor MOSFET N-CH 30V 18A PT8</p>	 <p>FDMS0309AS_SN00347 AMI Semiconductor / ON Semiconductor MOSFET N-CH</p>

heiße Teile

Mehr

 FDMF8705	 FDMQ8203	 FDMQ8203	 FDMQ8403	 FDMQ8403
 FDMS015N04B	 FDMS015N04B	 FDMS0300S	 FDMS0300S	 FDMS0302S
 FDMS0302S	 FDMS0306AS	 FDMS0306AS	 FDMS0306S	 FDMS0306S
 FDMS0308AS	 FDMS0308AS	 FDMS0308CS	 FDMS0308CS	 FDMS0308S
 FDMS0309AS	 FDMS0309AS	 FDMS030N06B	 FDMS030N06B	 FDMS0310AS
 FDMS0310S	 FDMS0310S	 FDMS0312AS	 FDMS0312AS	 FDMS0312S
 FDMS0312S	 FDMS0343S	 FDMS0346	 FDMS0348	 FDMS0349
 FDMS0351S	 FDMS0352S	 FDMS0354S	 FDMS0355AS	 FDMS0364S
 FDMS037N08B	 FDMS037N08B	 FDMS039N08B	 FDMS039N08B	 FDMS2380
 FDMS2380	 FDMS2506SDC	 FDMS2506SDC	 FDMS2572	 FDMS2572

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